

PW3134T

20V N-Channel MOSFET

0.75A 20V; $R_{DS(ON)typ}=190m\Omega@4.5V$, $R_{DS(ON)typ}=260m\Omega@2.5V$,
 $R_{DS(ON)typ}=390m\Omega@1.8V$

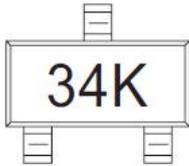
FEATURE

- Surface Mount Package
- N-Channel Switch with Low $R_{DS(on)}$
- Operated at Low Logic Level Gate Drive
- ESD Protected

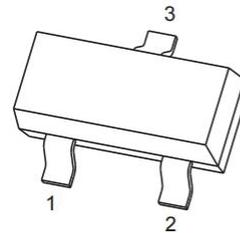
Application

- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

MARKING

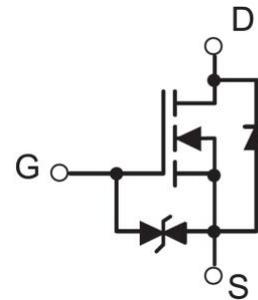


SOT-23



1. GATE
2. SOURCE
3. DRAIN

Schematic diagram



ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current ⁽¹⁾	I_D	0.75	A
Pulsed Drain Current ($t_p=10\mu s$)	I_{DM}	1.8	A
Power Dissipation ⁽¹⁾	P_D	0.35	W
Thermal Resistance from Junction to Ambient ⁽¹⁾	$R_{\theta JA}$	357	$^{\circ}C/W$
Junction Temperature	T_J	150	$^{\circ}C$
Storage Temperature	T_{STG}	-55~ +150	$^{\circ}C$
Lead Temperature for Soldering Purposes(1/8" duration for 10 s)	T_L	260	$^{\circ}C$

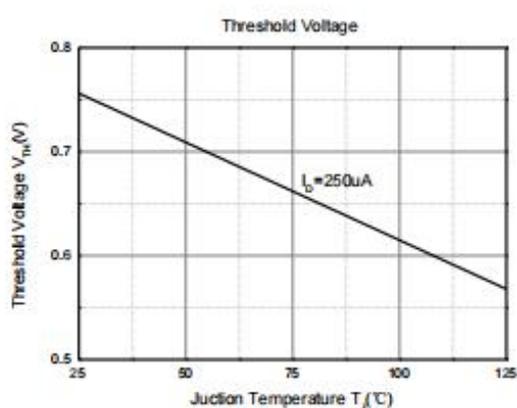
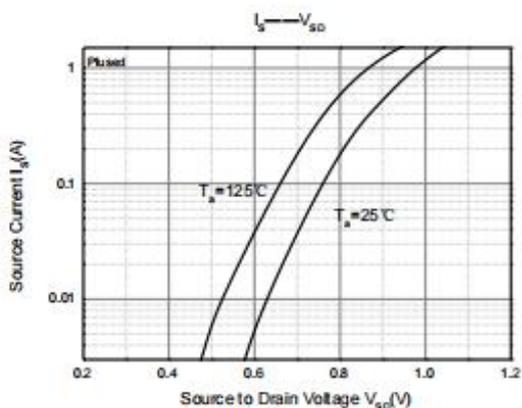
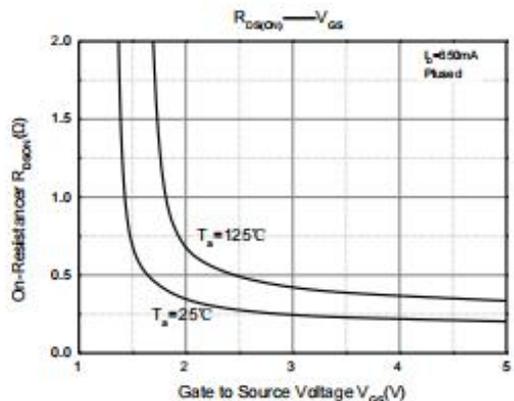
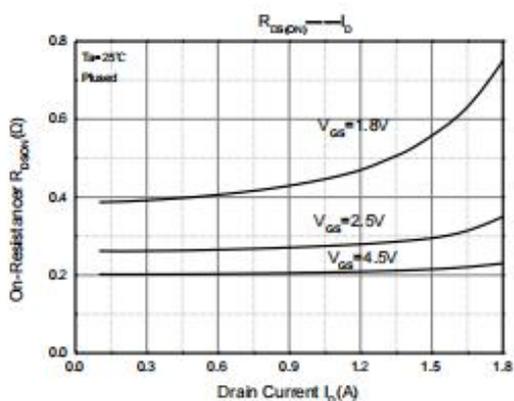
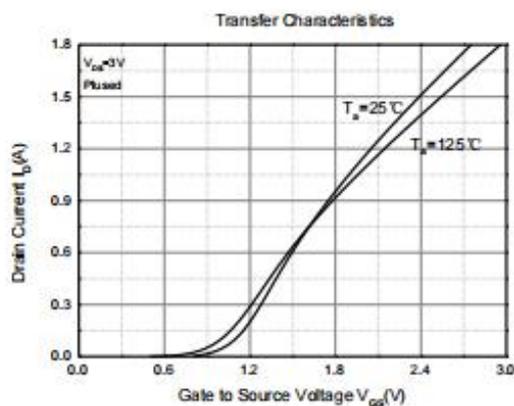
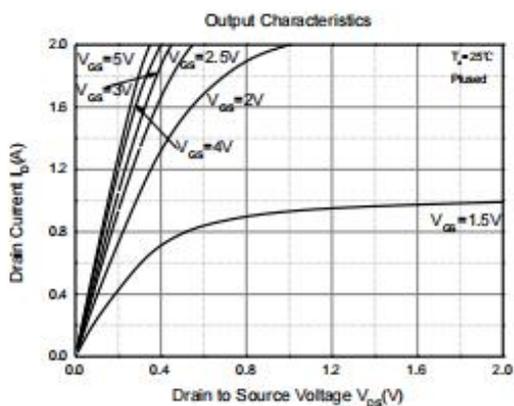
MOSFET ELECTRICAL CHARACTERISTICS(T_a=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 250μA	20			V
Zero gate voltage drain current	I _{DSS}	V _{DS} = 20V, V _{GS} = 0V			1	μA
Gate-body leakage current	I _{GSS}	V _{GS} = ±10V, V _{DS} = 0V			±20	μA
Gate threshold voltage ⁽²⁾	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250μA	0.35	0.75	1.1	V
Drain-source on-resistance ⁽²⁾	R _{DS(on)}	V _{GS} = 4.5V, I _D = 0.65A		190	260	mΩ
		V _{GS} = 2.5V, I _D = 0.55A		260	360	
		V _{GS} = 1.8V, I _D = 0.45A		390	590	
Forward tranconductance ⁽²⁾	g _{FS}	V _{DS} = 10V, I _D = 0.8A		1.6		S
DYNAMIC CHARACTERISTICS⁽⁴⁾						
Input Capacitance	C _{iss}	V _{DS} = 16V, V _{GS} = 0V, f = 1MHz		79	120	pF
Output Capacitance	C _{oss}			13	20	
Reverse Transfer Capacitance	C _{rss}			9	15	
SWITCHING CHARACTERISTICS⁽⁴⁾						
Turn-on delay time ⁽³⁾	t _{d(on)}	V _{GS} = 4.5V, V _{DS} = 10V, I _D = 500mA, R _{GEN} = 10Ω		6.7		ns
Turn-on rise time ⁽³⁾	t _r			4.8		
Turn-off delay time ⁽³⁾	t _{d(off)}			17.3		
Turn-off fall time ⁽³⁾	t _f			7.4		
SOURCE-DRAIN DIODE CHARACTERISTICS⁽⁴⁾						
Body Diode Voltage	V _{DS}	I _S = 0.15A, V _{GS} = 0V			1.2	V

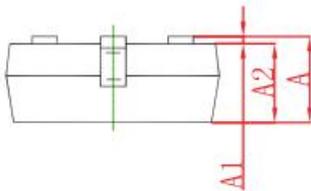
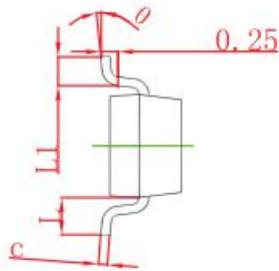
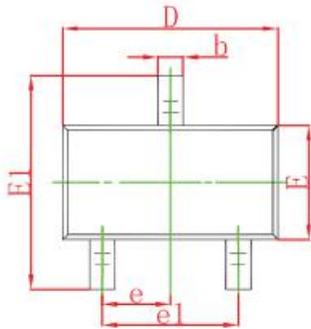
Notes:

1. Surface mounted on FR4 board using the minimum recommended pad size.
2. Pulse Test : Pulse Width=300μs, Duty Cycle=2%.
3. Switching characteristics are independent of operating junction temperatures.
4. Guaranteed by design, not subject to producing.

Typical Electrical and Thermal Characteristics



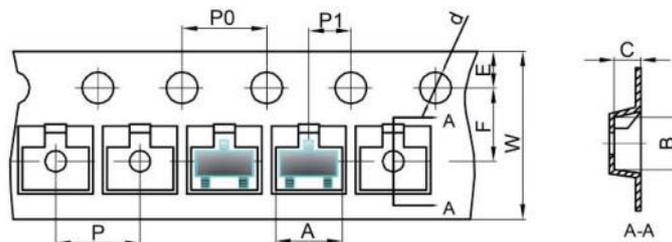
SOT-23 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

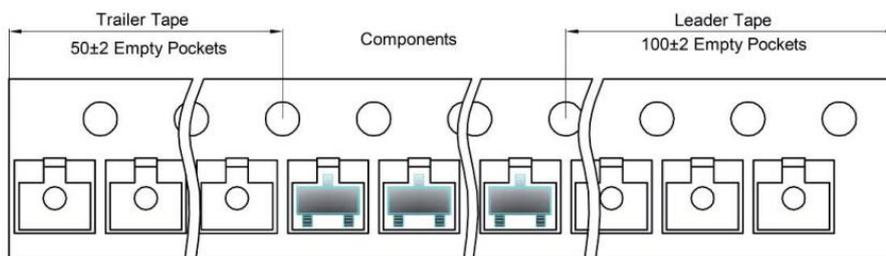
SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape

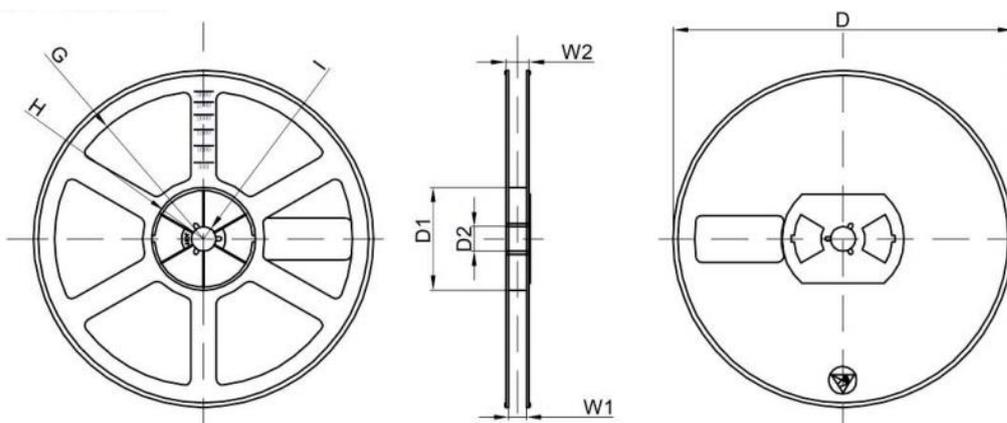


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer



SOT-23 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	